



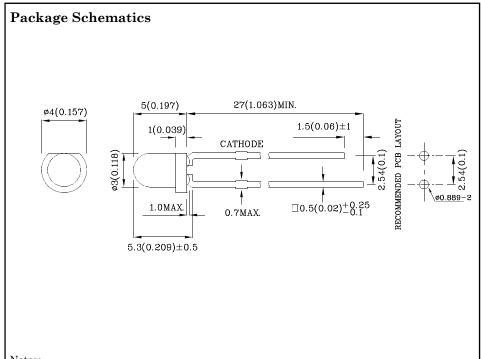
# T-1 (3mm) INFRARED EMITTING DIODE

## **Features**

- Radial / Through hole package
- $\bullet$  Reliable & robust
- Low power consumption
- Available on tape and reel
- RoHS Compliant







### Notes:

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is  $\pm 0.25(0.01")$  unless otherwise noted.
- 3. Specifications are subject to change without notice.

Absolute Maximum Ratings (T <sub>A</sub> =25°C)		THI/860 (GaAlAs)	Unit		
Reverse Voltage	$V_{\mathrm{R}}$	5	V		
Forward Current	$I_{\mathrm{F}}$	50	mA		
Forward Current (Peak) 1/10 Duty Cycle 0.1ms Pulse Width	iFS	1000	mA		
Power Dissipation	$P_{\mathrm{D}}$	80	mW		
Operating Temperature	T <sub>A</sub> -40 ~ +85		9.0		
Storage Temperature	Tstg	-40 ~ +85	°C		
Lead Solder Temperature [2mm Below Package Base]	260°C For 3 Seconds				
Lead Solder Temperature [5mm Below Package Base]	260°C For 5 Seconds				

Operating Characteristics (T <sub>A</sub> =25°C)	THI/860 (GaAlAs)	Unit	
Forward Voltage (Typ.) (I <sub>F</sub> =20mA)	$V_{\mathrm{F}}$	1.35	V
Forward Voltage (Max.) (I <sub>F</sub> =20mA)	$ m V_{F}$	1.6	V
Reverse Current (Max.) $(V_R=5V)$	${ m I}_{ m R}$	10	uA
Wavelength of Peak Emission CIE127-2007* (Typ.) (I <sub>F</sub> =20mA)	λΡ	860*	nm
Spectral Line Full Width At Half-Maximum (Typ.) (I <sub>F</sub> =20mA)	$\triangle \lambda$	50	nm
Capacitance (Typ.) (V <sub>F</sub> =0V, f=1MHz)	С	30	pF

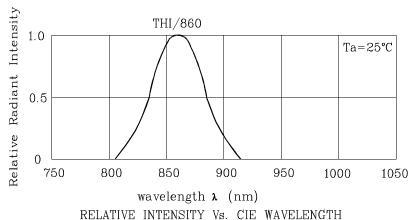
Part Number	Emitting Material	Lens-color	Radiant Intensity CIE127-2007* (Po=mW/sr) @20mA		(Po=mW/sr) $(Po=mW/sr)$		Wavelength CIE127-2007* Nm λP	Viewing Angle 20 1/2
			min.	typ.	min.	typ.		
XTHI30BF860	GaAlAs	Blue Transparent	8*	15*	15*	49*	860*	50°

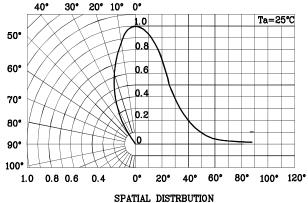
<sup>\*</sup>Radiant intensity value and wavelength are in accordance with CIE127-2007 standards.

XDSA2677 V7-Z Layout: Maggie L.

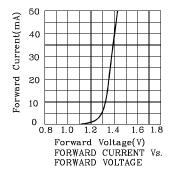


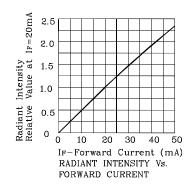


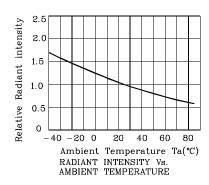




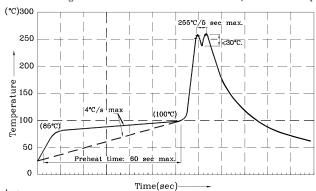
## **❖** THI/860







Wave Soldering Profile For Thru-Hole Products (Pb-Free Components)



Notes: Notes. I. Recommend pre-heat temperature of 105°C or less (as measured with a thermocouple attached to the LED pins) prior to immersion in the solder wave with a maximum solder bath temperature of  $260^{\circ}C$  2. Peak wave soldering temperature between  $245^{\circ}C \sim 255^{\circ}C$  for 3 sec

(5 sec max).

 $3.\mathrm{Do}$  not apply stress to the epoxy resin while the temperature is above  $85^{\circ}\mathrm{C}$ .  $4.\mathrm{Fixtures}$  should not incur stress on the component when mounting and

during soldering process. 5.SAC 305 solder alloy is recommended.

6. No more than one wave soldering pass

#### Remarks:

If special sorting is required (e.g. binning based on forward voltage, luminous intensity / luminous flux),

the typical accuracy of the sorting process is as follows:

1. Radiant Intensity / Luminous Flux: +/-15%

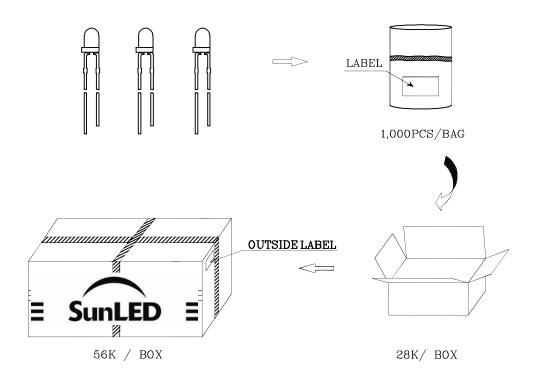
2. Forward Voltage: +/-0.1V

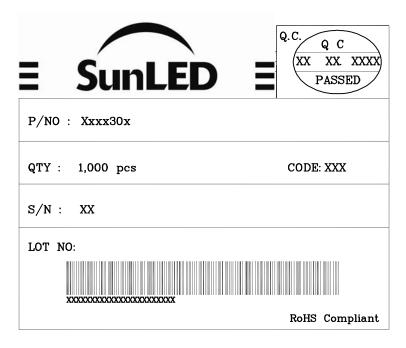
Note: Accuracy may depend on the sorting parameters.





# PACKING & LABEL SPECIFICATIONS





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